

T493D476K025CB6430

Aliases (DLA Drawing 07016-131KCBC)

T493 HRA, Tantalum, MnO2 Tantalum, HRA, 47 uF, 10%, 25 VDC, SMD, MnO2, Molded, DLA Drawing, C (0.01%/1000 Hrs), 120 mOhms, 3.1 mm, 2817 / 7343



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General Information

Series	T493 HRA
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, DLA Drawing
RoHS	Yes
Termination	Gold
Typical Component Weight	412.33 mg

Dimensions

L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
H	2.8mm +/-0.3mm
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	500

Specifications

Capacitance	47 uF
Tolerance	10%
Voltage DC	25 VDC (85C), 16.75 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	C (0.01%/1000 Hrs)
ESR	0.12 Ohms (100kHz 25C)
Ripple Current	926 mA (rms, 100kHz 25C)
Leakage Current	11.8 uA (5min 25°C)
Testing and Reliability	10 Cycles Surge Current Testing At -55C +/-5C And +85C +/-5C Before Weibull

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